

TOSHIBA Variable Capacitance Diode Silicon Epitaxial Planar Type

1SV279

VCO for V/UHF Band Radio

Unit: mm

- High capacitance ratio: $C_2/V/C_{10}/V = 2.5$ (typ.)
- Low series resistance: $r_s = 0.2 \Omega$ (typ.)
- Useful for small size tuner.

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Reverse voltage	V_R	15	V
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~125	$^\circ\text{C}$

JEDEC	—
JEITA	—
TOSHIBA	1-1G1A

Weight: 0.0014 g (typ.)

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse voltage	V_R	$I_R = 1 \mu\text{A}$	15	—	—	V
Reverse current	I_R	$V_R = 15 \text{ V}$	—	—	3	nA
Capacitance	C_2/V	$V_R = 2 \text{ V}, f = 1 \text{ MHz}$	14	—	16	pF
Capacitance	C_{10}/V	$V_R = 10 \text{ V}, f = 1 \text{ MHz}$	5.5	—	6.5	pF
Capacitance ratio	$C_2/V/C_{10}/V$	—	2.0	2.5	—	—
Series resistance	r_s	$V_R = 5 \text{ V}, f = 470 \text{ MHz}$	—	0.2	0.4	Ω

Marking

